imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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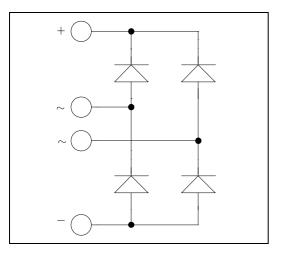


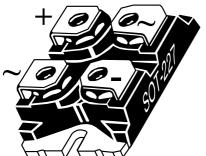


APT30DF20HJ

ISOTOP[®]Fast Diode Full Bridge Power Module

$V_{RRM} = 200V$ $I_F = 30A$ (a) $Tc = 80^{\circ}C$





Application

- Switch mode power supplies rectifier
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
- High level of integration
- ISOTOP[®] Package (SOT-227)

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit	
V _R	Maximum DC reverse Voltage			200	V	
V _{RRM}	Maximum Peak Repetitive Reverse	e Voltage			200	v
т	Maximum Average Forward	Dute and	500/	$T_C = 25^{\circ}C$	45	
$\mathbf{I}_{\mathrm{F}(\mathrm{AV})}$	Current	Duty cycle	e = 50%	$T_C = 80^{\circ}C$	30	А
I _{FSM}	Non-Repetitive Forward Surge Cu	etitive Forward Surge Current		$T_J = 45^{\circ}C$	320	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
\mathbf{V}_{F}	Diode Forward Voltage	$I_F = 30A$			1.1	1.3	V
		$I_F = 60A$			1.4		
		$I_F = 30A$	$T_j = 125^{\circ}C$		0.9		
I _{RM}	Maximum Reverse Leakage Current	$V_{R} = 200V \qquad \frac{T_{i} = 25^{\circ}C}{T_{j} = 125^{\circ}C}$			250		
			$T_j = 125^{\circ}C$			500	μA
CT	Junction Capacitance	$V_R = 200V$			95		pF

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
t _{rr}	Reverse Recovery Time	$I_{F} = 30A$ $V_{R} = 133V$ $di/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		24		ns
۲r			$T_{j} = 125^{\circ}C$		48		
Q _{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		33		nC
Qrr			$T_{i} = 125^{\circ}C$		150		
I _{RRM}	Reverse Recovery Current		$T_j = 25^{\circ}C$		3		Α
IRRM			$T_{j} = 125^{\circ}C$		6		
t _{rr}	Reverse Recovery Time	$I_F = 30A$ $V_R = 133V$ $di/dt = 1000A/\mu s$			31		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 125^{\circ}C$		355		nC
I _{RRM}	Reverse Recovery Current				19		А

Thermal and package characteristics

Symbol	Characteristic	Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal resistance			1.2	°C/W
R _{thJA}	Junction to Ambient			20	C/ W
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz	2500			V
T_J, T_{STG}	Storage Temperature Range	-55		150	°C
$T_{\rm L}$	Max Lead Temp for Soldering:0.063" from case for 10 sec			300	C
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)			1.5	N.m
Wt	Package Weight		29.2		g

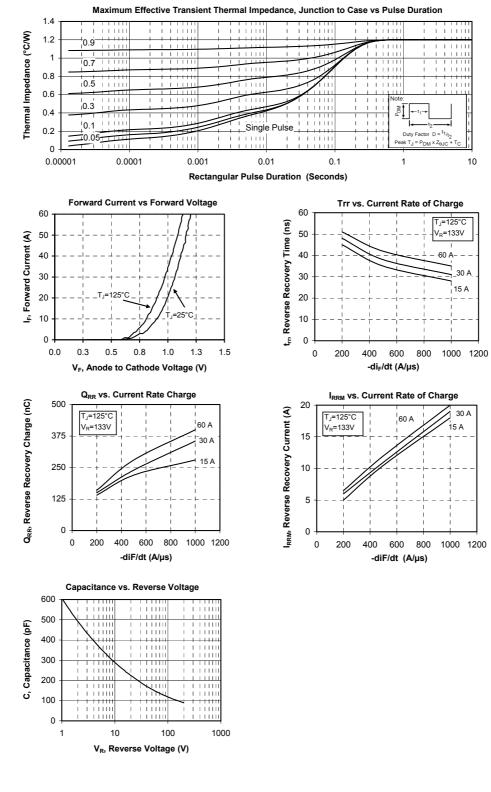
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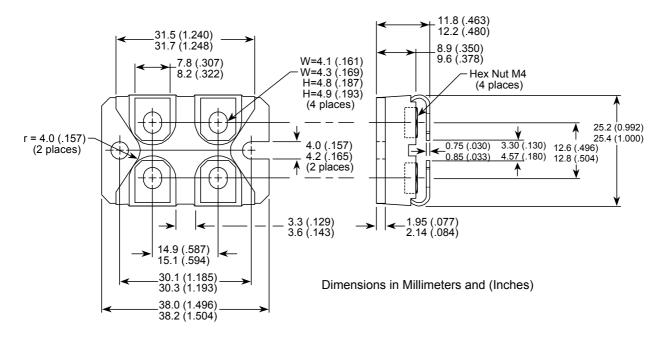
Typical Performance Curve



APT30DF20HJ - Rev 2 October, 2012



SOT-227 (ISOTOP[®]) Package Outline



ISOTOP® is a registered trademark of ST Microelectronics NV



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